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April 1st, 2010 Renesas Electronics Corporation

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M66257FP 5120 × 8-Bit × 2 Line Memory (FIFO)

REJ03F0251-0200 Rev.2.00 Sep 14, 2007

Description

The M66257FP is a high-speed line memory with a FIFO (First In First Out) structure of 5120-word \times 8-bit double configuration which uses high-performance silicon gate CMOS process technology.

It allows simultaneous output of 1-line delay data and 2-line delay data, and is most suitable for data correction over multiple lines.

It has separate clock, enable and reset signals for write and read, and is most suitable as a buffer memory between devices with different data processing throughput.

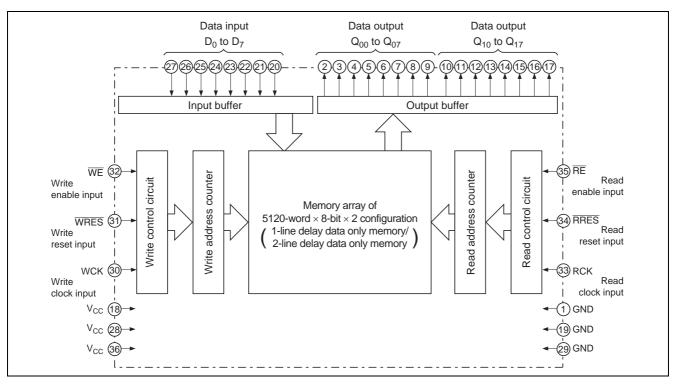
Features

- Memory configuration: 5120 words × 8 bits × 2 (dynamic memory)
- High-speed cycle: 25 ns (Min)
- High-speed access: 18 ns (Max)
- Output hold: 3 ns (Min)
- Fully independent, asynchronous write and read operations
- Output: 3 states
- Q_{00} to Q_{07} : 1-line delay
- Q_{10} to Q_{17} : 2-line delay

Application

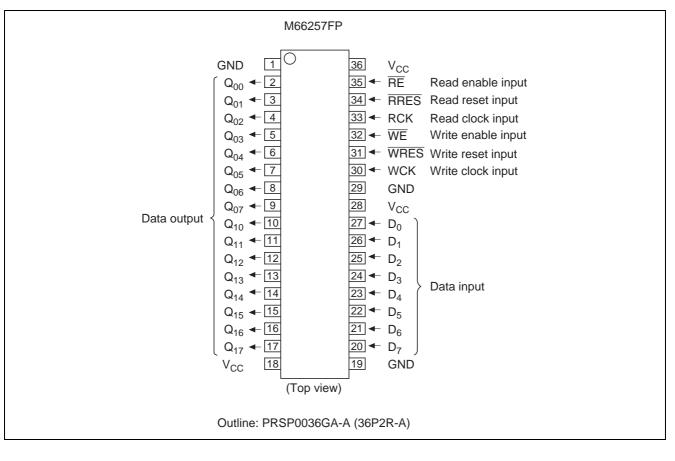
Digital photocopiers, high-speed facsimile, laser beam printers.

Block Diagram



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Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 0 \text{ to } 70^{\circ}C, \text{ unless otherwise noted})$

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	–0.5 to +7.0	V	A value based on
Input voltage	V ₁	-0.5 to V _{CC} + 0.5	V	GND pin
Output voltage	Vo	-0.5 to V _{CC} + 0.5	V	
Power dissipation	Pd	660	mW	Ta = 25°C
Storage temperature	Tstg	-65 to 150	°C	

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	Vcc	4.5	5	5.5	V
Supply voltage	GND	_	0	_	V
Operating ambient temperature	Topr	0		70	°C

Electrical Characteristics

	(Ta = 0 to 70°	°C, V _{CC}	$= 5 \text{ V} \pm 1$	10%, GN	ND = 0 V, ur	lless otherwise noted)
Item	Symbol	Min	Тур	Max	Unit	Tes	st Conditions
"H" input voltage	VIH	2.0	_	_	V		
"L" input voltage	VIL			0.8	V		
"H" output voltage	V _{OH}	$V_{CC}-0.8$	_	_	V	I _{OH} = -4 m	A
"L" output voltage	V _{OL}		_	0.55	V	$I_{OL} = 4 \text{ mA}$	
"H" input current	l _{iн}	_		1.0	μA	V _I = V _{CC}	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
"L" input current	l _{IL}	_		-1.0	μA	V _I = GND	$\overline{\text{WE}}$, $\overline{\text{WRES}}$, WCK, RE, RRES, RCK, D ₀ to D ₇
Off state "H" output current	I _{OZH}		_	5.0	μA	$V_{O} = V_{CC}$	
Off state "L" output current	I _{OZL}		_	-5.0	μΑ	$V_0 = GND$	
Operating mean current dissipation	Icc		_	120	mA	$V_I = V_{CC}, G$	SND, Output open
						t _{wcк} , t _{RCK} =	= 25 ns
Input capacitance	Cı			10	pF	f = 1 MHz	
Off state output capacitance	Co			15	pF	f = 1 MHz	

Function

When write enable input $\overline{\text{WE}}$ is "L", the contents of data inputs D₀ to D₇ are written into 1-line delay data only memory in synchronization with rise edge of write clock input WCK. At this time, the write address counter of 1-line delay data only memory is also incremented simultaneously.

The write functions given below are also performed in synchronization with rise edge of WCK.

When $\overline{\text{WE}}$ is "H", a write operation to 1-line delay data only memory is inhibited and the write address counter of 1-line delay data only memory is stopped.

When write reset input WRES is "L", the write address counter of 1-line delay data only memory is initialized.

When read enable input $\overline{\text{RE}}$ is "L", the contents of 1-line delay data only memory are output to data outputs Q_{00} to Q_{07} and those of 2-line delay data only memory to data outputs Q_{10} to Q_{17} in synchronization with the rise of read clock input RCK. At this time, the read address counters of 1-line and 2-line delay data only memories is also incremented simultaneously.

Moreover, data of Q_{00} to Q_{07} are written into 2-line delay data only memory in synchronization with rise edge of RCK. At this time, the write address of 2-line delay data only memory is incremented.

The read functions given below are also performed in synchronization with rise edge of RCK.

When $\overline{\text{RE}}$ is "H", a read operation from both of 1-line delay data only memory and 2-line delay data only memory is inhibited and the read address counter of each memory is stopped. The outputs of Q_{00} to Q_{07} and Q_{10} to Q_{17} are in the high impedance state.

Moreover, a write operation to 2-line delay data only memory is inhibited and the write address counter of 2-line delay data only memory is stopped.

When read reset input \overline{RRES} is "L", the read address counter of 1-line delay data only memory, and the write address counter and read address counter of 2-line delay data only memory are initialized.

Switching Characteristics

$(Ta = 0 \text{ to } 70^{\circ}\text{C}, V_{CC} = 5 \text{ V} \pm 10\%, \text{ GND} = 0 \text{ V}, \text{ unless otherwise note}$					
Item	Symbol	Min	Тур	Max	Unit
Access time	t _{AC}			18	ns
Output hold time	t _{OH}	3		_	ns
Output enable time	t _{OEN}	3		18	ns
Output disable time	todis	3		18	ns

Timing Conditions

	(Ta = 0 to	$70^{\circ}C, V_{CC} = 5$	$5 \text{ V} \pm 10\%, \text{GN}$	D = 0 V, unle	ss otherwise noted)
Item	Symbol	Min	Тур	Max	Unit
Write clock (WCK) cycle	t _{wcк}	25			ns
Write clock (WCK) "H" pulse width	t _{wcкн}	11			ns
Write clock (WCK) "L" pulse width	t _{WCKL}	11	—		ns
Read clock (RCK) cycle	t _{RCK}	25	—		ns
Read clock (RCK) "H" pulse width	t _{RCKH}	11	—		ns
Read clock (RCK) "L" pulse width	t _{RCKL}	11	—		ns
Input data setup time to WCK	t _{DS}	7	—		ns
Input data hold time to WCK	t _{DH}	3		—	ns
Reset setup time to WCK or RCK	t _{RESS}	7	—		ns
Reset hold time to WCK or RCK	t _{RESH}	3			ns
Reset nonselect setup time to WCK or RCK	t _{NRESS}	7			ns
Reset nonselect hold time to WCK or RCK	t _{NRESH}	3	—		ns
WE setup time to WCK	t _{WES}	7	—		ns
WE hold time to WCK	t _{WEH}	3	—		ns
WE nonselect setup time to WCK	t _{NWES}	7	—		ns
WE nonselect hold time to WCK	t _{NWEH}	3	—		ns
RE setup time to RCK	t _{RES}	7	—		ns
RE hold time to RCK	t _{REH}	3			ns
RE nonselect setup time to RCK	t _{NRES}	7			ns
RE nonselect hold time to RCK	t _{NREH}	3			ns
Input pulse rise/fall time	tr, tf	_		20	ns
Data hold time*	t _H			20	ms

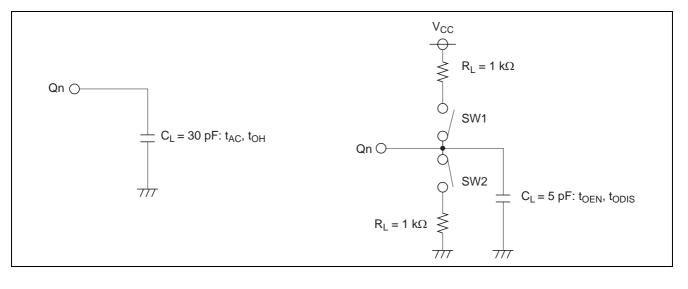
Notes: Reset the IC after power is turned on.

* For 1-line access, the following should be satisfied:

 $\overline{\text{WE}}$ "H" level period < 20 ms – 5120 t_{WCK} – $\overline{\text{WRES}}$ "L" level period

 $\overline{\text{RE}}$ "H" level period $< 20\mbox{ ms}-5120\mbox{ }t_{\text{RCK}}-\overline{\text{RRES}}$ "L" level period

Test Circuit



Input pulse level: 0 to 3 V

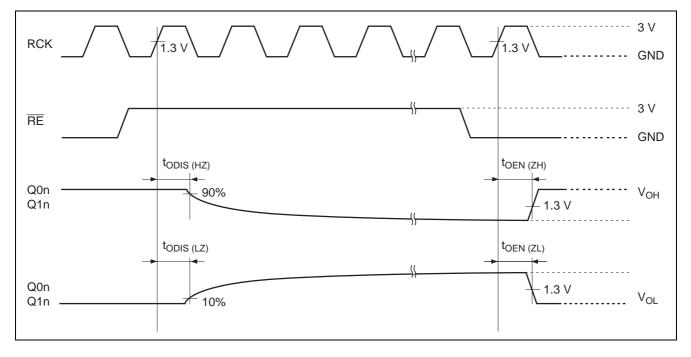
Input pulse rise/fall time: 3 ns

Decision voltage input: 1.3 V

Decision voltage output: 1.3 V (However, t_{ODIS (LZ)} is 10% of output amplitude and t_{ODIS (HZ)} is 90% of that for decision)

The load capacitance C_L includes the floating capacitance of connection and the input capacitance of probe.

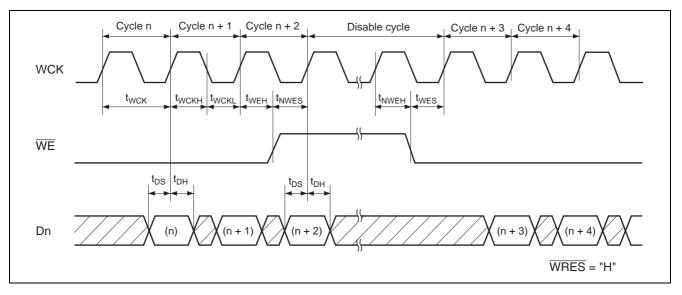
Parameter	SW1	SW2
t _{ODIS (LZ)}	Closed	Open
t _{odis (HZ)}	Open	Closed
t _{OEN (ZL)}	Closed	Open
t _{OEN (ZH)}	Open	Closed



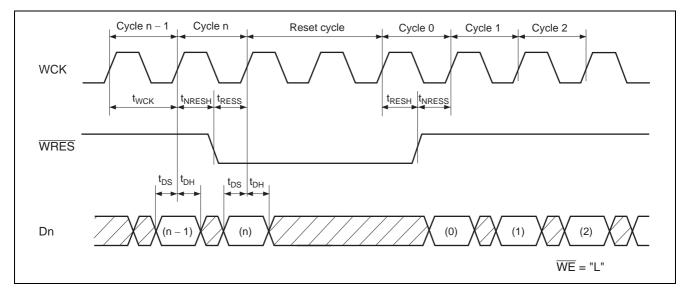
t_{ODIS}/t_{OEN} Test Condition

Operating Timing

Write Cycle

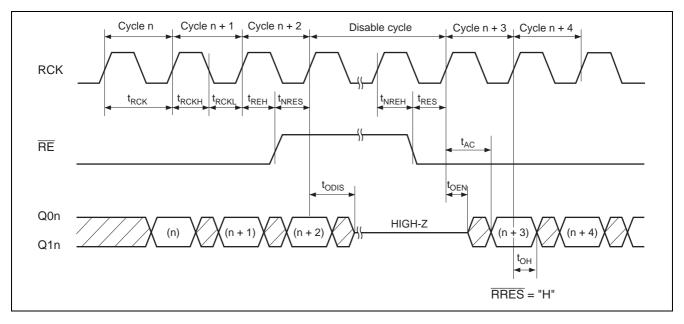


Write Reset Cycle

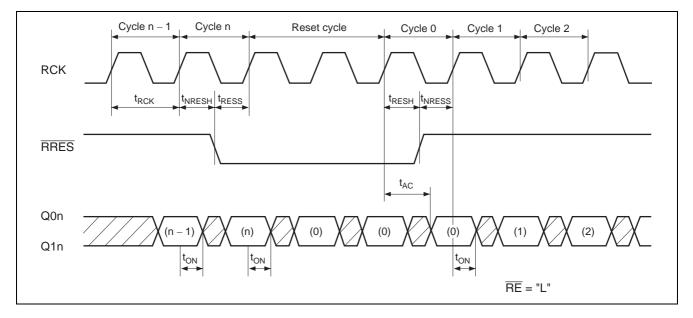


M66257FP

Read Cycle

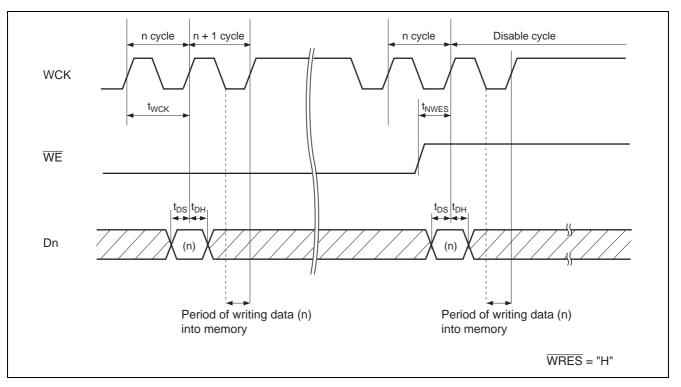


Read Reset Cycle



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Note at WCK Stop



Input data Dn of n cycle is read at the rising edge after WCK of n cycle. Writing operation starts in the "L" period of WCK of n + 1 cycle and ends at the rising edge after n + 1 cycle.

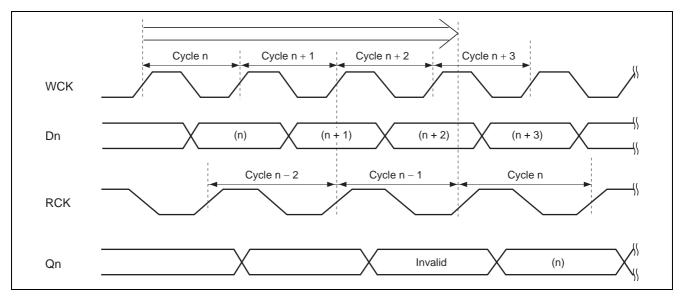
To stop reading write data at n cycle, input WCK for up to the rising edge of n + 1 cycle.

When the cycle next to n cycle is a disable cycle, input of WCK for a cycle is required after a disable cycle as well.

Shortest Read of Data "n" Written in Cycle n

(Cycle n - 1 on read side should be started after end of cycle n + 1 on write side)

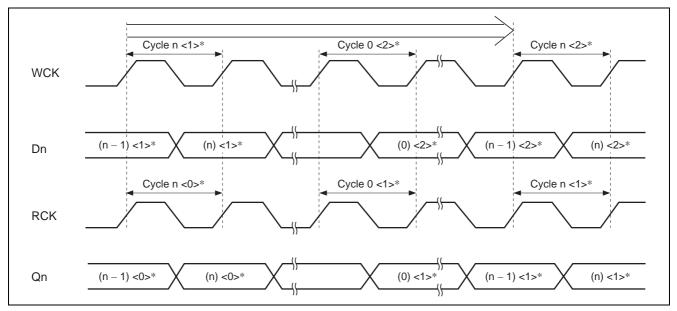
When the start of cycle n - 1 on read side is earlier than the end of cycle n + 1 on write side, output Qn of cycle n becomes invalid. In the figure shown below, the read of cycle n - 1 is invalid.



Longest Read of Data "n" Written in Cycle n: 1-line Delay

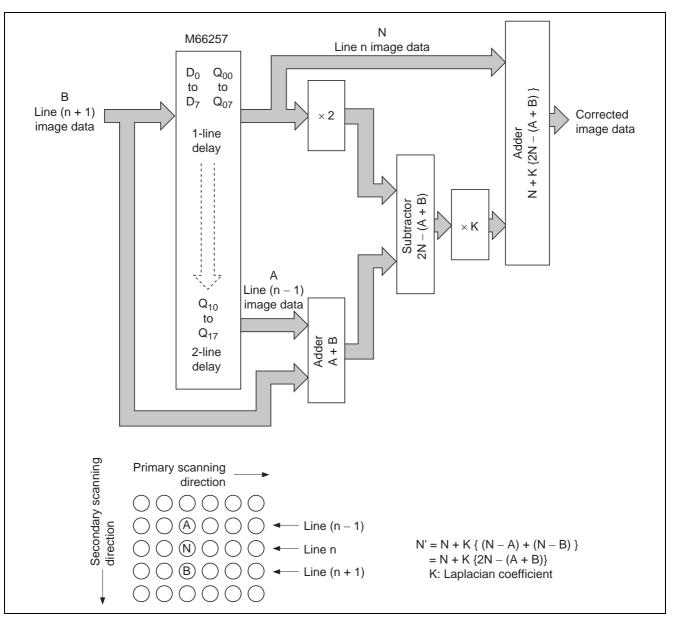
(Cycle n <1>* on read side should be started when cycle n <2>* on write is started)

Output Qn of n cycle <1>* can be read until the start of reading side n cycle <1> and the start of writing side n cycle <2>* overlap each other.



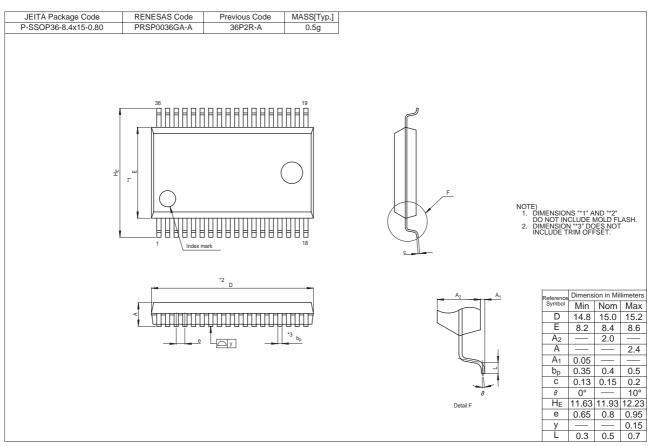
Note: <0>*, <1>* and <2>* indicates a line value.

Application Example



Laplacian Filter Circuit for Correction of Resolution in the Secondary Scanning Direction

Package Dimensions



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